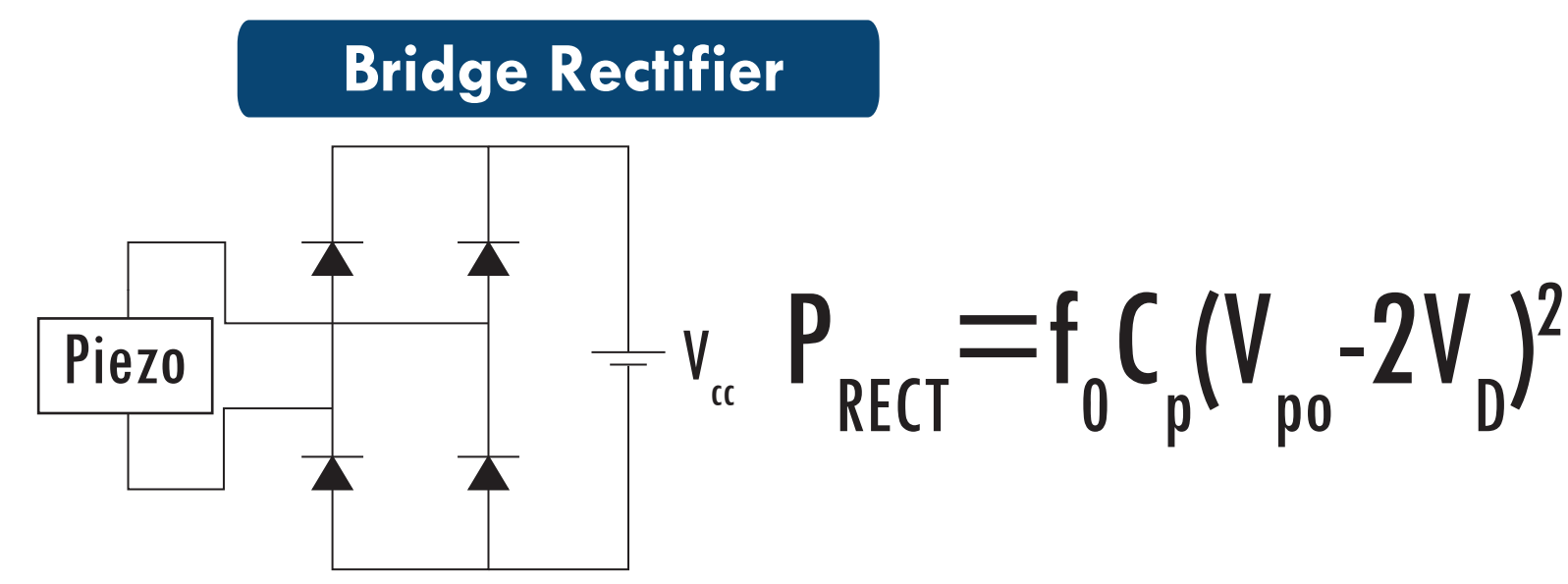


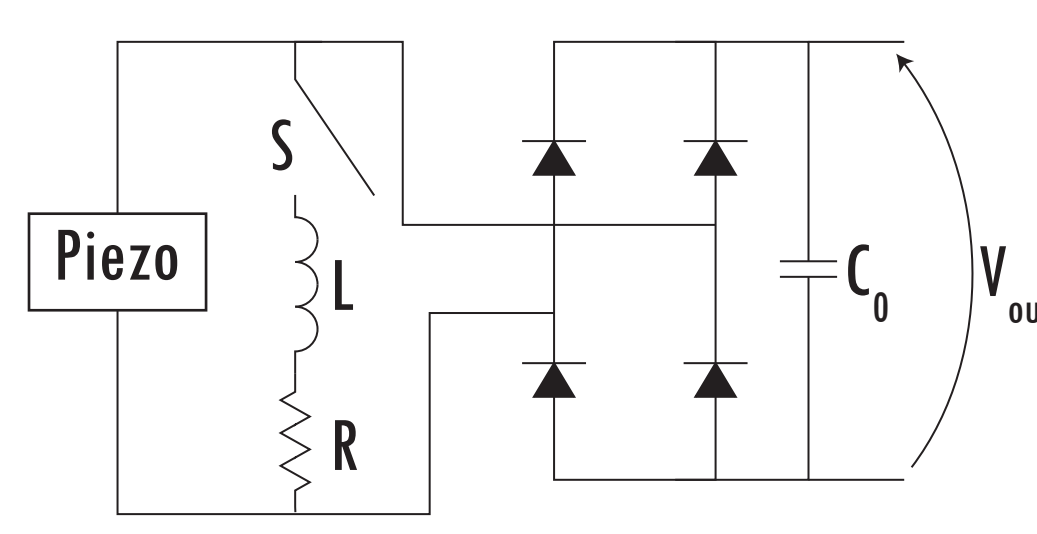
Motivation and Theory

- Improving the power density of energy harvesters is critical to increasing functionality of self-powered sensors.
- Improvements to the interface circuit can increase the power density of piezoelectric harvesters.
- Charge modification techniques have successfully increased the output power limit under situations where high electrical damping is required.
- Here a technique called Single Supply Pre-biasing (SSPB) is described which has twice the theoretical output power limit of any other circuit.



V_{cc} set to optimal output voltage [3].

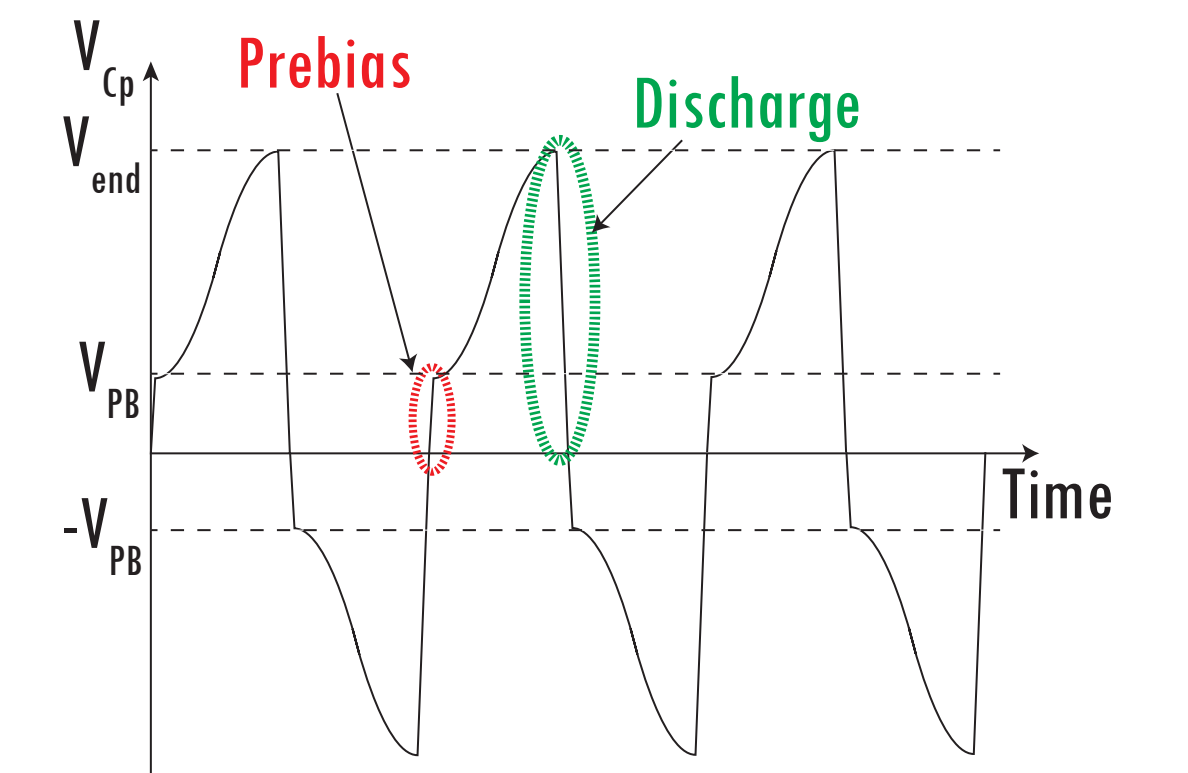
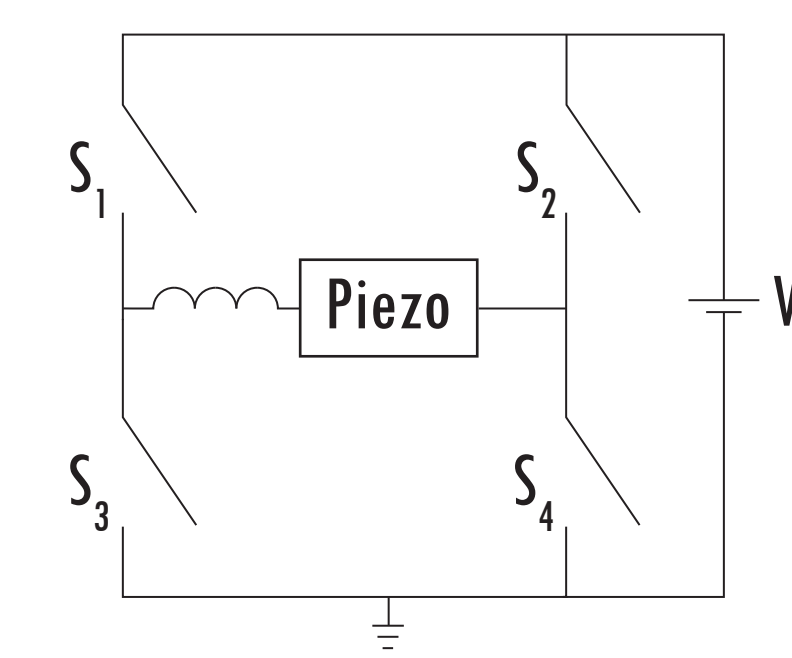
$$P_{SSH-DC} = V_{po}^2 f_0 C_p (4Q/\pi)$$



Flips the charge on the piezo beam at the extreme points of travel. However a rectifier is still required to extract power [1].

Candidate Interface Circuits

Single Supply Pre-biasing

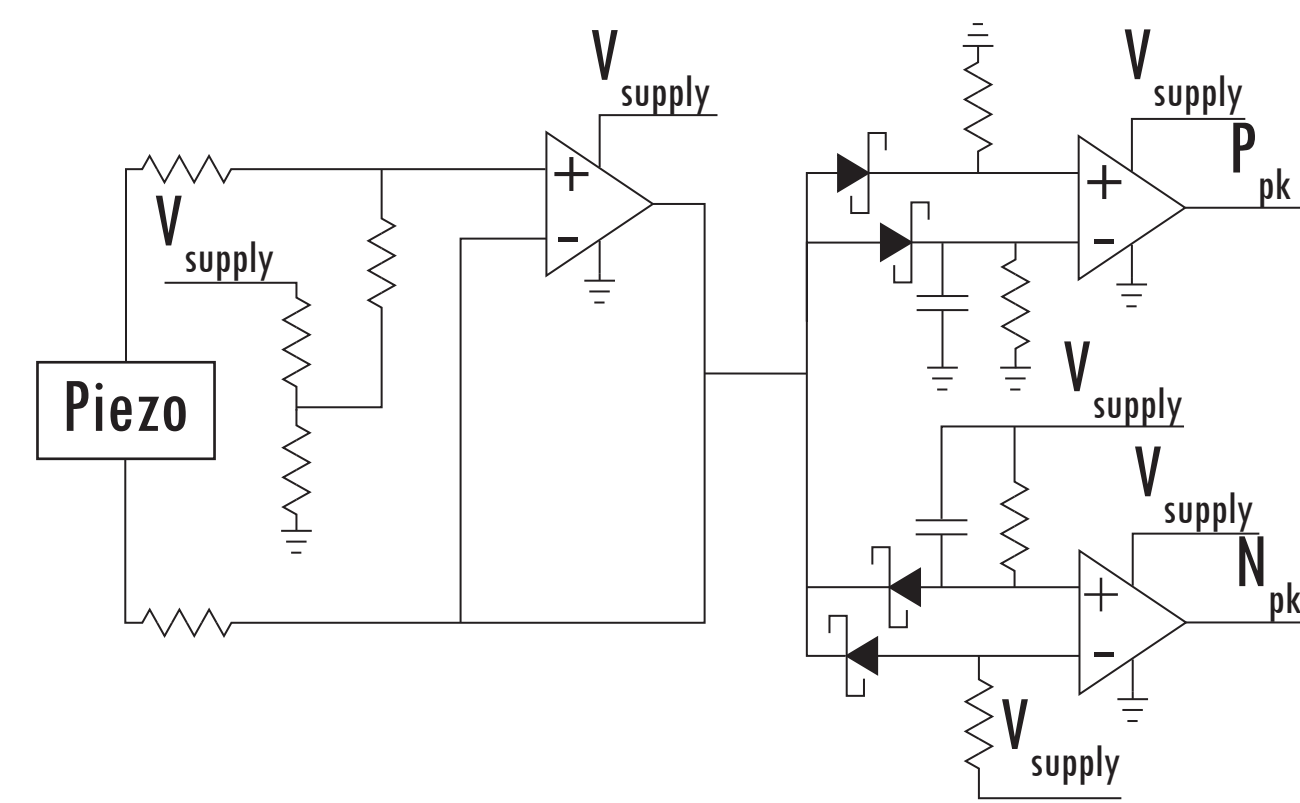


- Piezoelectric material is pre-biased at travel extremes with V_{pb} (polarity dependent upon maxima and minima position) by closing a switch pair (e.g. S_1 & S_3) briefly.
- Piezo then moves to its opposite extreme, thus causing the voltage on C_p to increase further, V_{end} .
- Same switch pair briefly closes again, discharging the piezo into V_{cc} before opposite switch pair (S_2 & S_4) are closed applying V_{pb} with the opposite polarity and repeating the cycle [3].

$$P_{SSPB} = V_{po}^2 f_0 C_p (8Q/\pi)$$

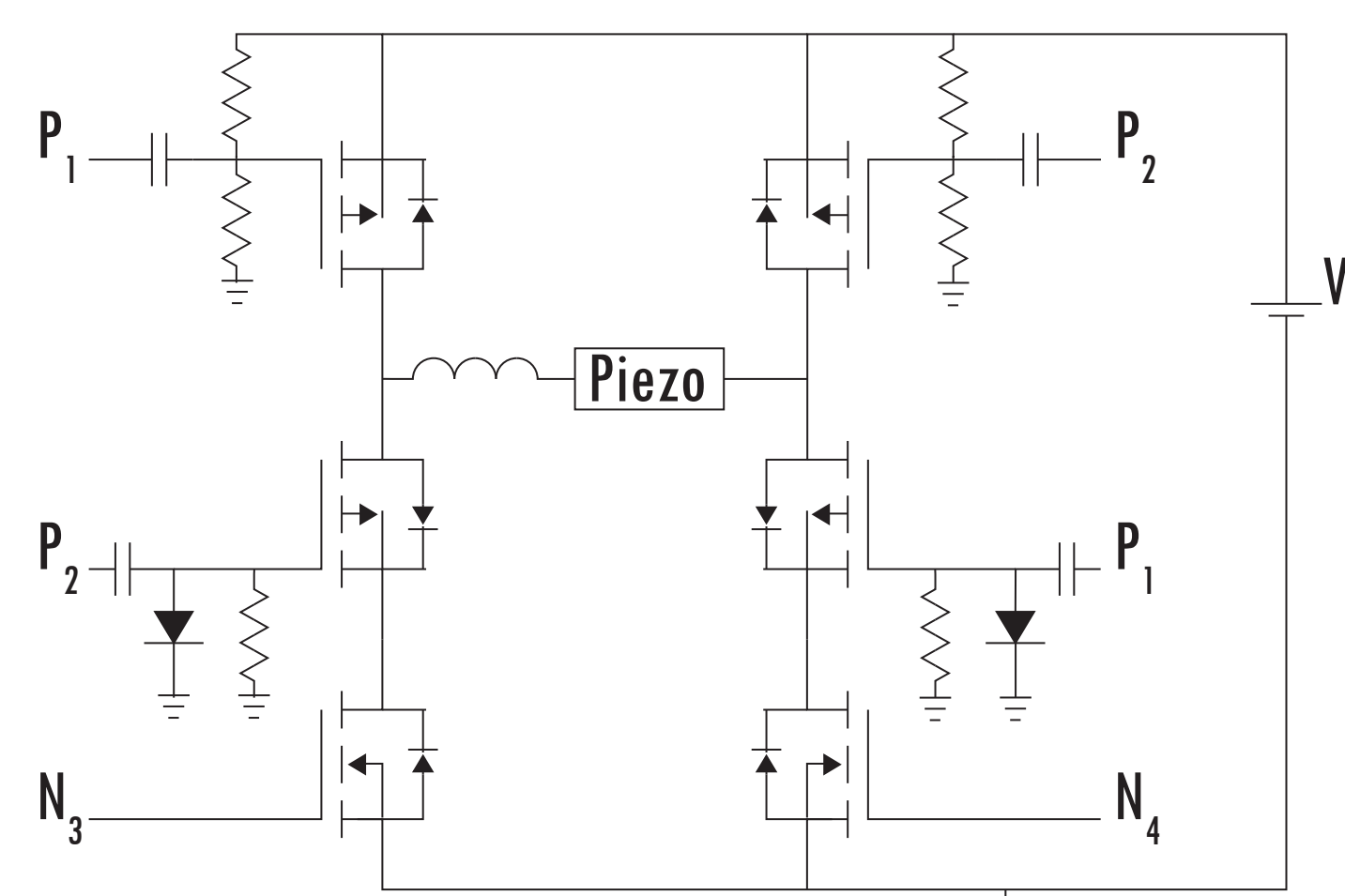
[1] D. Guyomar, A. Badel, E. Lefeuvre, and C. Richard, "Toward energy harvesting using active materials and conversion improvement by non-linear processing," IEEE Transactions on Ultrasonics, Ferroelectrics and Frequency Control, vol. 52, no. 4, pp. 584–595, April 2005.

Peak detection circuit



Instantaneous differential sense piezo voltage compared with lossy peak-hold copy to detect peaks [2].

Resonant H-bridge circuit

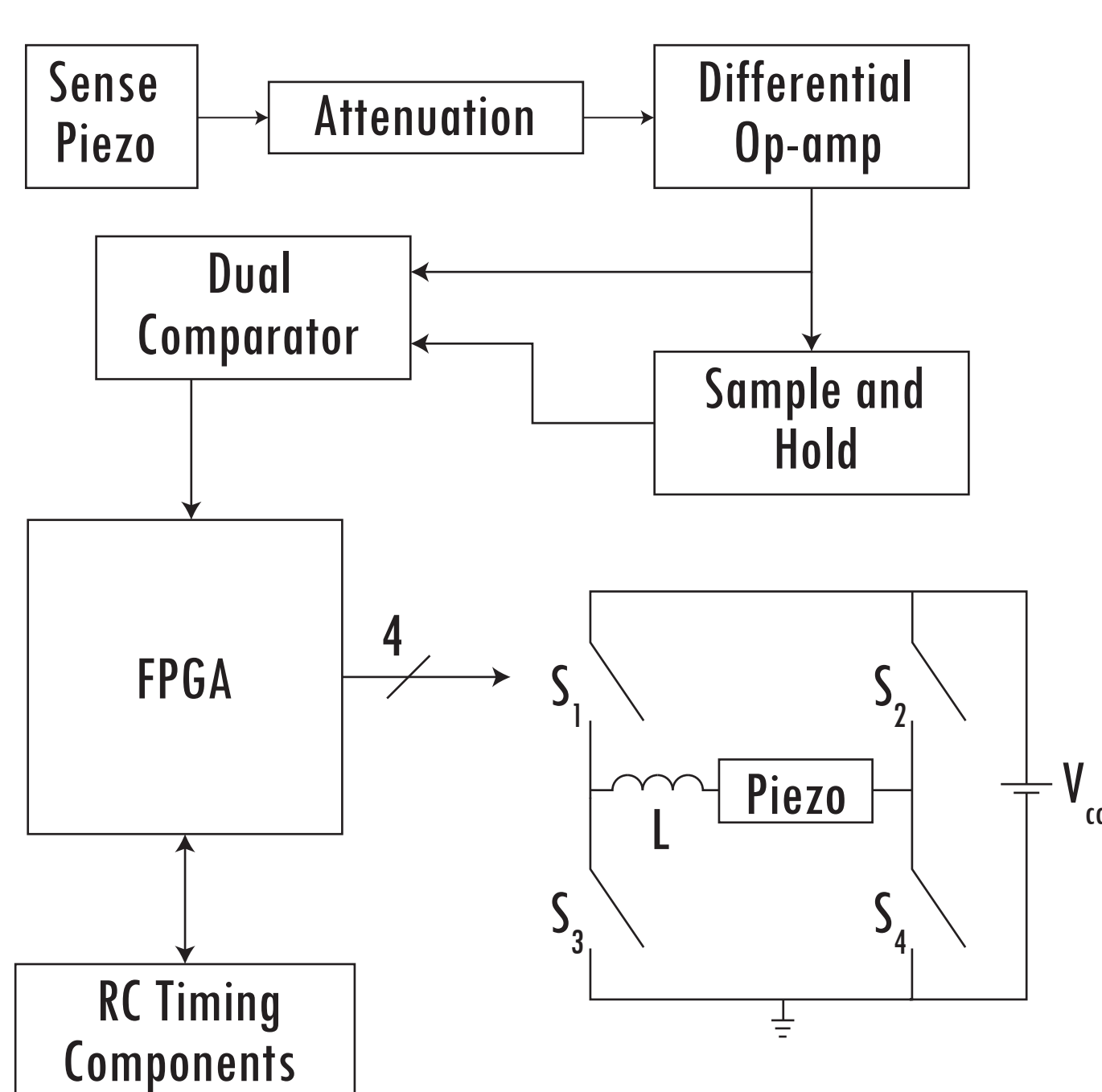


Switching circuit implemented from a H-bridge, p-type and n-type MOSFETs connected in series to form bi-directional blocking and conducting switches.

SSPB Practical Design

- Crucial switches are fired at travel extremes corresponding to voltage waveform extremes.
- A second piezo mechanically coupled but electrically isolated from generation piezo provided in-phase sense voltage for determining switch firing.
- Switches held on for one electrical resonance half cycle (ensures zero current conditions) by micro-power FPGA triggered by peak detector with time delay set by external resistor and capacitor.
- Series connected n-type and p-type MOSFETs create bidirectional conducting and blocking switches required for operation whilst, minimising switch voltage drop.

High level SSPB circuit implementation

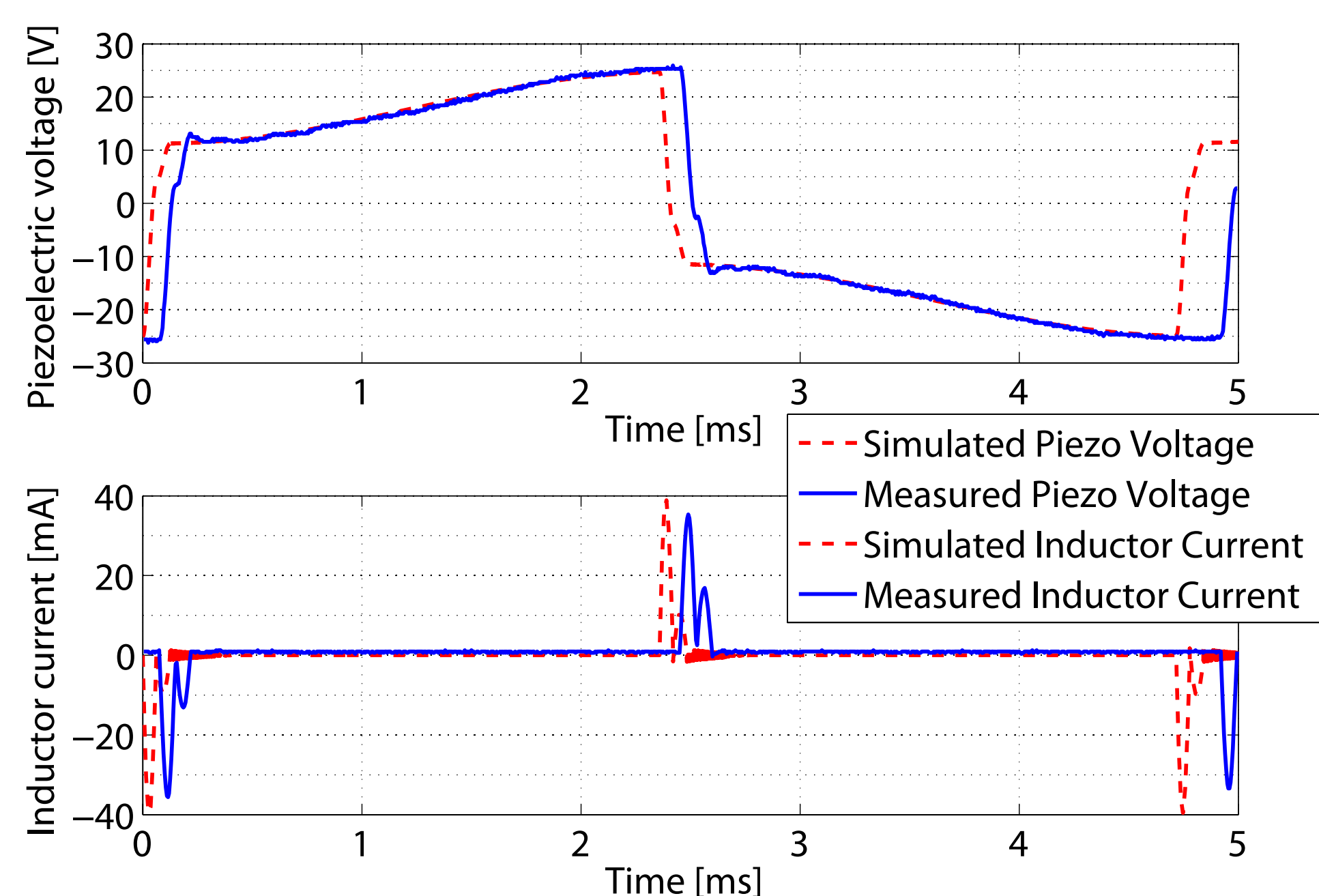


[2] A. D. T. Elliott and P. D. Mitcheson, "Implementation of a single supply pre-biasing circuit for piezoelectric energy harvesters," in EuroSensors 2012, September 2012.

Results and Future Work

- Output power of SSPB and bridge rectifier interface circuits were measured under optimal conditions.
- Harvester excited at 212 Hz with different peak accelerations (corresponding to different piezo open circuit voltages V_{po}).
- SSPB generated 11.3 times more power than bridge rectifier and 14% more than SSHI theoretical limit.
- Control power expenditure 126 μ W (76% due to peak detector).
- Future work on peak detector power reduction and implementing maximum power point tracking.

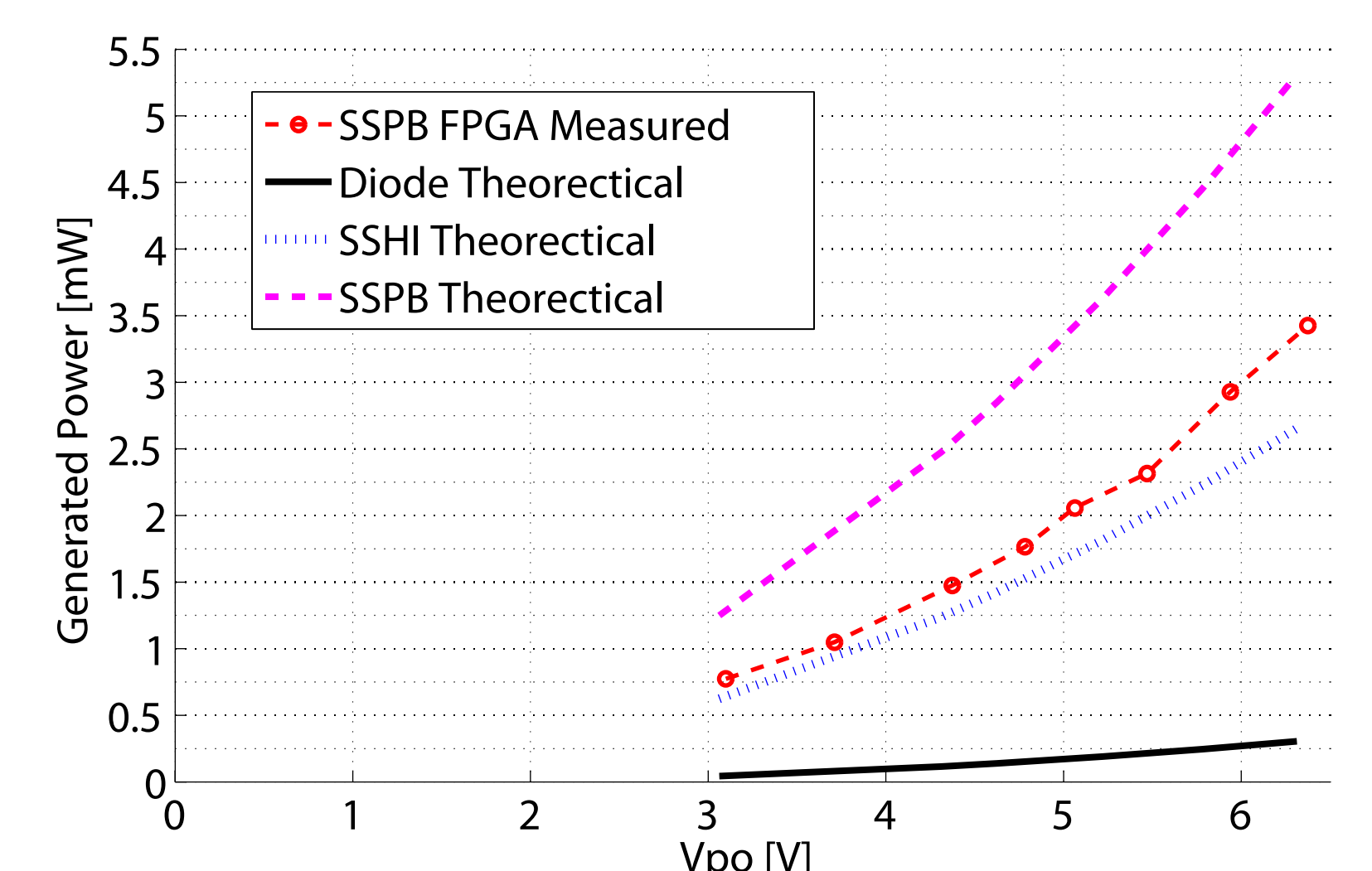
Piezo voltage and inductor current waveforms



Measured and PSpice generated waveforms of the piezoelectric capacitor voltage and inductor current.

$$P_{SSPBmeasured} = 1.14 \times P_{SSHTheoretical}$$

$$P_{SSPBmeasured} = 11.3 \times P_{RECTTheoretical}$$



Measured SSPB power output after control overhead versus theoretical bridge rectifier, SSHI and SSPB maximum power extraction limit [3].

[3] J. Dicken, P. D. Mitcheson, I. Stoianov, and E. M. Yeatman, "Power-extraction circuits for piezoelectric energy harvesters in miniature and low-power applications," IEEE Transactions on Power Electronics, vol. 27, pp. 4514–4529, 2012.